

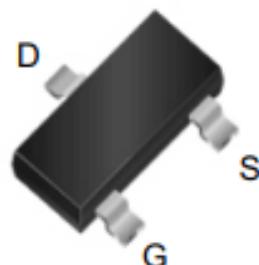
## SSC8037GS6A

P-Channel Enhancement Mode MOSFET

### ➤ Features

$V_{DS}$	$V_{GS}$	$R_{DS(ON)}\text{ Typ.}$	$I_D$
-30V	$\pm 20V$	21m $\Omega$ @-10V	-8A
		28m $\Omega$ @-4V5	

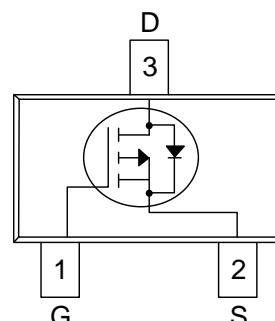
### ➤ Pin configuration



SOT-23-3L

### ➤ Description

The SSC8037GS6A is P-Channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent RDSON with low gate charge. This device is suitable for use in load switch, DCDC conversion and battery isolation.



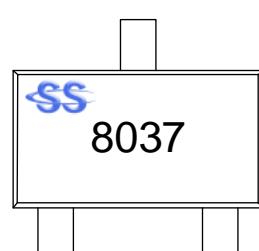
Pin Configuration (Top View)

### ➤ Applications

- Load Switch
- DCDC Conversion
- Battery Isolation

### ➤ Ordering Information

Device	Package	Shipping
SSC8037GS6A	SOT-23-3L	3000/Reel



Marking

➤ Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$  unless otherwise noted)

Symbol	Parameter	Ratings	Unit
$V_{DSS}$	Drain-to-Source Voltage	-30	V
$V_{GSS}$	Gate-to-Source Voltage	$\pm 20$	V
$I_D$	Continuous Drain Current <sup>a</sup>	-8	A
$I_{DM}$	Pulsed Drain Current <sup>b</sup>	-28	A
$P_D$	Power Dissipation <sup>a</sup>	2.2	W
$T_J$	Operation junction temperature	-55~150	$^\circ\text{C}$
$T_{STG}$	Storage temperature range	-55~150	$^\circ\text{C}$

➤ Thermal Resistance Ratings ( $T_A=25^\circ\text{C}$  unless otherwise noted)

Symbol	Parameter	Ratings	Unit
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance <sup>a</sup>	58	$^\circ\text{C}/\text{W}$

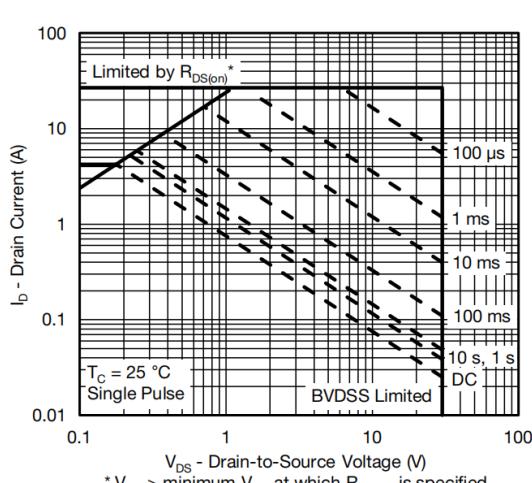
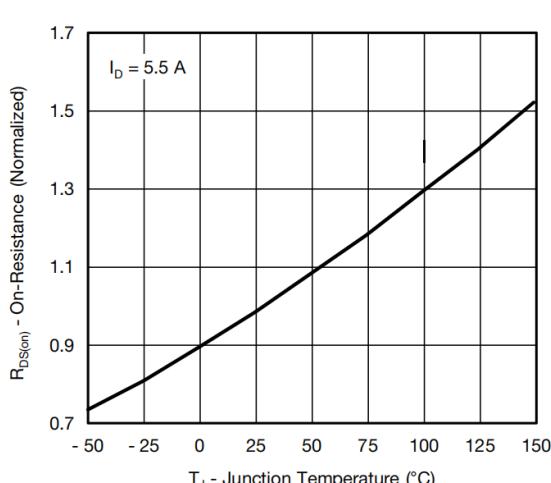
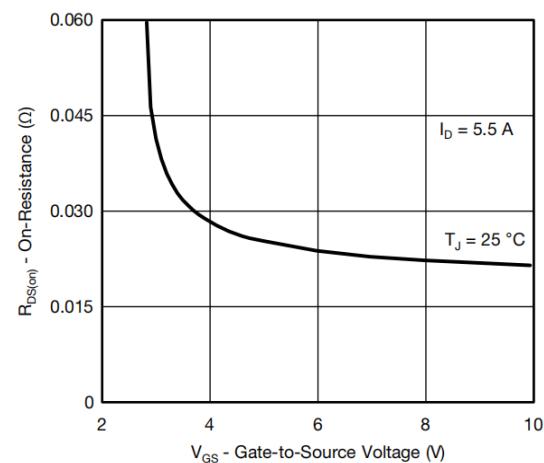
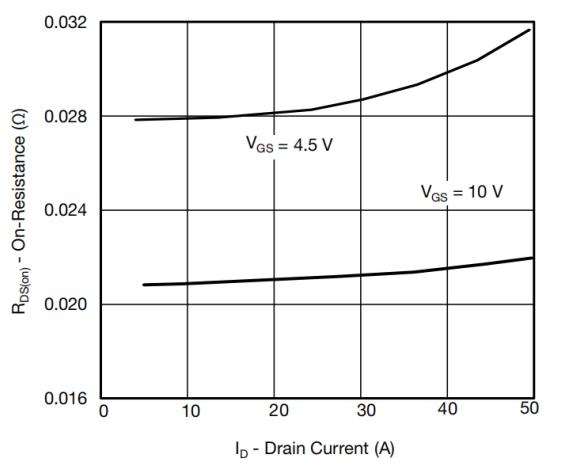
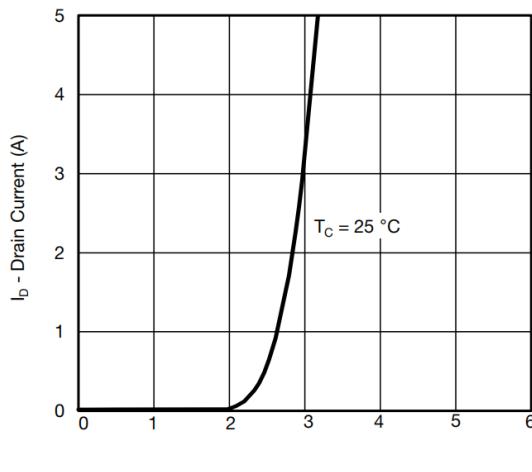
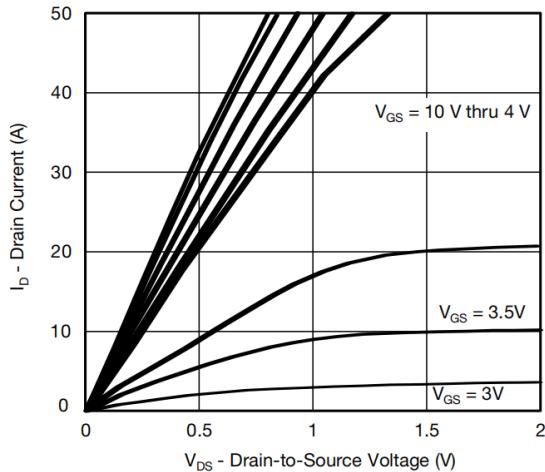
Note:

- a. The value of  $R_{\theta JA}$  is measured with the device mounted on 1 in<sup>2</sup> FR-4 board with 2oz.copper, in a still air environment with  $T_A=25^\circ\text{C}$ . The value in any given application depends on the user's specific board design. The power dissipation is based on the  $t \leq 10\text{s}$  thermal resistance rating.
- b. Repetitive rating, pulse width limited by junction temperature.

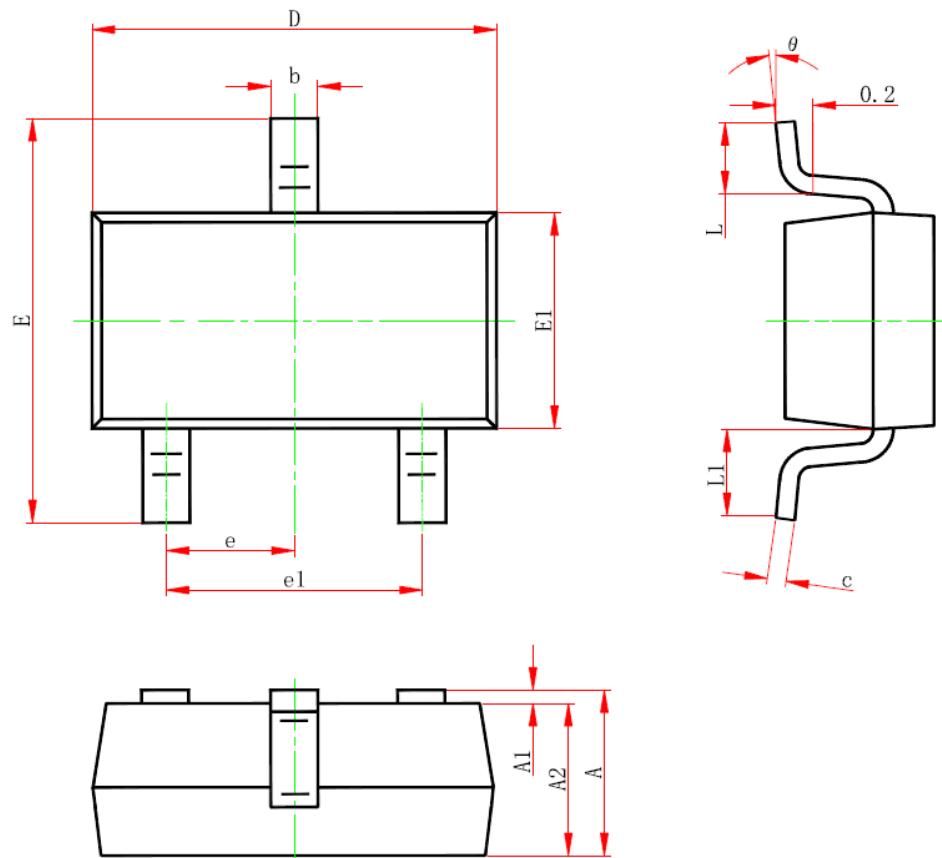
➤ Electrical Characteristics ( $T_A=25^\circ C$  unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-30			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-1	-1.6	-3	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -5A$		21	28	$m\Omega$
		$V_{GS} = -4.5V, I_D = -3A$		28	42	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -30V, V_{GS} = 0V$			-1	$\mu A$
Gate-Source Leak Current	$I_{GSS}$	$V_{GS} = \pm 20V, V_{DS} = 0V$			$\pm 100$	nA
Transconductance	$G_{FS}$	$V_{DS} = -10V, I_D = -5A$		15		s
Forward Voltage	$V_{SD}$	$V_{GS} = 0V, I_S = -3A$		-0.8	-1.3	V
Input Capacitance	$C_{ISS}$	$V_{DS} = -15V, V_{GS} = 0V,$ $f = 1MHz$		1300		$pF$
Output Capacitance	$C_{OSS}$			162		
Reverse Transfer Capacitance	$C_{RSS}$			183		
Turn-on Delay Time	$T_{D(ON)}$	$V_{GS} = -10V, V_{DS} = -15V,$ $R_L = 3\Omega, R_G = 1\Omega$		8.3		$ns$
Rise Time	$T_r$			33.8		
Turn-off Delay Time	$T_{D(OFF)}$			49		
Fall Time	$T_f$			10.6		
Total Gate Charge	$Q_G$	$V_{GS} = -10V, V_{DS} = -15V,$ $I_D = -2A$		25		$nC$
Gate to Source Charge	$Q_{GS}$			4.5		
Gate to Drain Charge	$Q_{GD}$			6.2		

➤ Typical Performance Characteristics ( $T_A=25^\circ\text{C}$  unless otherwise noted)



## ➤ Package Information


Package: SOT-23-3L

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
L1	0.600REF.		0.024REF.	
θ	0°	8°	0°	8°

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